Superconducting in Equal Molar NbTaTiZr-Based High-Entropy Alloys

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Keywords: HEAs, Superconducting, Matthias' Rule, e/a, NbTaTiZr-Based Alloys, Fe, Ge, Hf, Si, V Addition,

Coherence Length, Electrical Carrier Density

Received: January 4, 2018 Accepted: March 27, 2018 Published: March 30, 2018

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ABSTRACT

Superconducting (SC) in equal molar NbTaTiZr-based high-entropy alloys (HEAs) that were added with Fe, Ge, Hf, Si, and/or V was observed. According to investigation on crystal structure, composition, and the relationship between critical temperature and e/a ratio, as indicated in Matthias' empirical rule, the main superconducting phase was that enriched with Nb and Ta. The coherence length (ξ) that was calculated from the carrier density reveals that ξ value has the same order of magnitude of several hundreds of Angstroms as those binary Nb-Ti and Nb-Zr alloys showed.

1. INTRODUCTION

In the absence of an applied magnetic field, the electrical resistivity of a superconductor tends to zero upon cooling to a critical temperature, T_c [1]. As the temperature falls to T_o and when the applied magnetic field is weaker than a critical field, H_o the magnetic flux is completely expelled from the superconductor, and a perfect diamagnetic state is formed [2]. Superconductors with these properties have been widely studied and applied in various applications.

Among elements in nature, Nb has the highest T_c (9.25 K). Conventional binary Nb-based alloys, such as Nb-Ti (~10 K), Nb-Zr (~11 K), Nb₃Sn (18 K), and Nb₃Ge (23 K), have even a higher T_c than Nb [3]. These T_c values are too low to enable the elements to be used under ambient conditions. Therefore, many attempts have been made to raise T_c . For example, researchers have used various heat treatments to control the formation of the superconducting phase of, e.g., Nb-Zr, [4]. In Nb-Ti [5], as another example, third elements, Al & Mo, have been used to generate 4.6 to 4.8 valence electrons per atom, e/a [6]. According to Matthias' empirical rule, the highest T_c is obtained at the optimal e/a ratio for which the composition chooses, e.g., Mo, as a third element to reduce T_c in Nb-Ti [5]. However, adding Al promotes the formation of a phase of Nb-rich and increases T_c [5]. However, the T_c in ternary systems barely exceeds

that of binary Nb-Ti. Accordingly, the effectiveness of such approaches to increase T_c is limited. Moreover, Matthias' empirical rule may not be applicable to multi-phase alloys. Difficulties still exist.

High-entropy alloys (HEAs) were proposed in 1995. These alloys were obtained by vacuum arc remelting [7, 8]. The efforts to design and prepare HEAs have opened up yet another frontier in alloy research. They have been defined as alloys that contain principal elements of between five and 13 (inclusive), and have atomic concentrations of between five and 35 at% (inclusive). Their main characteristics are high solubility, a large degree of lattice distortion, a large point lattice defect effect, slow atom diffusion, and a composite property effect (the so-called cocktail effect). Thermodynamically, the high-entropy effect, is a TS factor and a physical effect overcomes the enthalpy effect, which is an H factor and a chemical effect, increasing the solubility of each of the principal elements, promoting the generation of a random simple pseudo-unitary solid solution, such as with the A1, A2, or A3 crystal structure. This tendency to form a simple random solid solution thermodynamically enables the slow diffusion of atoms in the working processes, as occurs in thermal treatments. Hence, a nanostructure can be easily obtained. The high solubility of constituent elements makes the random solid solution highly ductile and hard. The HEA can simultaneously have the properties that conventional alloys with fewer multi-principal-element alloys cannot easily have simultaneously, such as heat resistance, anticorrosion, anti-oxidation, and precipitation hardening at high temperatures. Therefore, HEAs have great potential in the development of a range of applications [9]. HEAs have superior physical properties such as electrical conductivity, magnetic permeability, thermal conductivity, and hydrogen storage [10, 11].

This study will explore superconductivity in HEAs. Multi-principal elements are added to modify their microstructure to study the effect of adding elements on the superconducting behaviors—zero electrical resistivity and diamagnetism—of simple pseudo-unitary BCC alloys [11]. The selected materials were equimolar NbTaTiZr-based HEAs. The results are compared with those for conventional superconductors.

2. THEORY

Superconductivity in conventional alloys has been microscopically explained by the BCS, which was proposed by Bardeen, Cooper, and Schrieffer in 1957 [12]. The central point of BCS is that electron Cooper pairs that are formed by electron-electron interaction under the influence of lattice phonon as the temperature falls below T_c generate no electrical resistivity. The critical temperature for superconductivity is given by, [13]

$$T_c = 1.14\theta_D \exp\left(\frac{-1}{\lambda}\right),\tag{1}$$

$$\lambda = D(\varepsilon_F)V, \qquad (2)$$

where λ is a superconducting coupling constant; $D(\varepsilon_F)$ is the electron density of states at the Fermi level; θ_D (= $\hbar\omega/k_B$) is the Debye temperature; k_B is Boltzmann's constant; ω is the frequency of lattice vibration, and V is of the interaction between electrons in Cooper pairs. BCS applies only in weak coupling condition, *i.e.*, $0 < \lambda \ll 1$. In 1968, McMillan developed another expression for T_c which considers the electron-phonon interaction, and is affected by both weak and strong couplings. This T_c is given by [14]

$$T_{c} = \frac{\theta_{D}}{1.45} \exp \left[\frac{-1.04(1+\lambda)}{\lambda - \mu^{*}(1+0.62\lambda)} \right],$$
 (3)

where θ_D is Debye temperature; λ is a coupling constant for the interaction between electrons and phonons, and μ^* is the repulsive coupling interaction constant in the interaction between electrons. McMillan also found that, for most metals, $\mu^* \approx 0.13$. Accordingly, Equation (3) can be simplified as:

$$T_c \approx \frac{\theta_D}{1.45} \exp\left[\frac{-(1+\lambda)}{\lambda}\right],$$
 (4)

$$\lambda = \frac{D(\varepsilon_F)\langle I \rangle^2}{M \langle \omega \rangle^2},\tag{5}$$

where I is the electron-phonon matrix element; ω is the phonon frequency in the metal lattice, and M is the mass of a metal ion. From Equation (5), a larger λ , associated with higher $D(\varepsilon_F)$, a smaller ω or a smaller θ_D , are associated with a higher T_c . For this reason, alloying elements are added. One paper on superconductivity in Nb-Cu noted that, as the temperature falls to T_i , the silky network of the superconducting phase begins to allow the Cooper pairs to pass the alloy, generating superconductivity [15]. As the temperature falls further to T_{β} if the coherence length is large enough, then the Cooper pairs generate an integrated superconducting path by the proximity effect. Therefore, determining whether superconducting HEAs exhibit the proximity effect and whether they are type II superconductors is essential. Some appropriate theories are used to calculate the coherence length (ξ) and the Ginzburg-Landau parameter (κ) from the carrier density [16]:

$$n = \frac{IB}{V_{u} qt}, \tag{6}$$

where n is the carrier density at 5 K; I is the current; B is the applied magnetic field; V_H is the Hall voltage; t is the thickness of sample; and q is the electric charge. After resistance vs. temperature (R-T) measurements were made to determine the electrical resistivity, the Drude model was used to calculate the electron relaxation time τ [16].

$$\rho = \frac{m}{nq^2\tau},\tag{7}$$

where ρ is the 300 K-resistivity; m is the electron mass; n is the carrier density; and q is the electric charge. The Fermi velocity v_F can also be obtained from the carrier density using Equation (8) [16].

$$\nu_F = \left(\frac{\hbar}{m}\right) (3\pi^2 n)^{\frac{1}{3}}.\tag{8}$$

The Fermi velocity and relaxation time can be used to determine the mean free path of the electrons using Equation (9) [16].

$$\ell = \nu_F \tau . (9)$$

Equations ((10) & (11)) yield the superconducting energy gap at 0 K, Δ (0), and the intrinsic coherence length, ξ_0 , respectively [17].

$$\Delta(0) = 1.76k_B T_c. \tag{10}$$

$$\xi_0 = \frac{\hbar \upsilon_F}{\pi \Delta(0)},\tag{11}$$

where k_B is Boltzmann's constant; T_c is the superconducting critical temperature; and \hbar is Planck's constant over 2π .

In the mixed state of type II superconductors, each Abrikosov vortex has a core radius, ξ , at normal conducting (NC) state, surrounded by an outer radius, λ , of superconducting current. Each vortex carries a quantized flux, $\Phi_0 = 2.0678 \times 10^{-7}$ G cm². As the applied magnetic field increases to the lower critical field, H_{cl} , vortices arise. Hence, the flux Φ_0 can be expressed as Equation (12) [16]:

$$\phi_0 \cong \pi \lambda^2 H_{c1}. \tag{12}$$

The Ginzburg-Landau parameter, κ , can thus be obtained and used to identify the type of a superconductor by applying Equation (13) [3].

$$\kappa = \frac{\lambda}{\xi} \,. \tag{13}$$

The existence of superconductivity in HEAs was demonstrated and the coherence length is shown to be of the order of several hundred Å, equal to that of binary Nb-Zr and Nb-Ti. Therefore, there is also a proximity effect like that in Nb-Zr and Nb-Ti, is suggested to exist in superconducting HEAs. The calculated κ value is 14.32. This value, taken with results of magnetic measurements, reveals that superconducting HEAs are type II superconductors. Notably, Fe-containing NbTaTiZrFe has $T_c = 6.87 \pm 0.03$ K. The highest obtained $T_c = 8.46 \pm 0.02$ K of NbTaTiZrGe [18] is close to that of element Nb of 9.25 K, the two values are near. This result is not good enough, but, owing to the many degrees of freedom in the design of alloys, superconducting HEAs may open up a new avenue for research and applications.

3. EXPERIMENTAL

JEOL 5410 SEM-energy-dispersed X-ray spectroscope (SEM-EDS) was used to observe the microstructure and analyze the composition of alloys. Shimadzu XRD 6000 diffractometer was used in X-ray diffraction with Cu-target (wavelength of 1.5405 Å), and operated at 30 kV and 20 mA. The scanning speed was 2° /min with a 2θ range of 20 to 100 degrees.

To measure the transition temperature, specimens were cut in rectangles with a length of 8 mm and width of 3 mm, and ground using #400 SiC grinding paper to a thickness of 0.2 mm. The four-point method was used to plot the resistivity vs. temperature, R(T), curves at 4.2 K to 300 K. The accuracy of the temperature measurement was better than ± 0.06 K. The critical transition temperature, T_c is defined as the temperature at which the resistivity drops to 50% of the total resistivity. The interval of transition is defined by the formula $\Delta T_c = T_c(90\%) - T_c(10\%)$, where 90% and 10% indicate a drop in the resistivity to 90% and 10% of the original value, respectively, in the transition.

A SQUID setup was used to obtain both magnetic susceptibility vs. temperature, $\chi(T)$, and magnetization vs. applied magnetic field, M(H). $\chi(T)$ at temperatures in the range 2 K to 300 K were obtained using the zero-field cooling (ZFC) method in applied magnetic fields of 100 Oe. Two fixed temperatures, 5 K and 300 K, were used and the applied field was cyclically varied from 0 to 1 to 0 to -1 to 0 T, and then back to 1 T. The lower magnetic field, H_{c1} , is the field that induces deviation from the diamagnetism ($\chi = -1$) line. When the demagnetization factor is considered, H_{c1} is given by Equation (14):

$$H_{c1} = \frac{H}{1 - D},\tag{14}$$

where D is demagnetization factor. The upper critical field, H_{c2} , is the smallest field that yields zero magnetization.

Hall measurements were made using a PPMS system (Quantum Design PPMS-9T) that was operated at 47 Hz, 50 mA AC, and from 9 T to -9 T at 10 K. Pt wires were attached using low-temperature Ag paste to the specimens to measure resistivity and to make the Hall measurements. The attachments were baked at 50°C to ensure an Ohmic contact. Carrier density was determined from the Hall voltage data.

Table 1 lists selected alloys, their phases, and their compositions. Both as-cast (C state) and homogenized (H state) specimens were used. Some designations are given. They are equal-molar C4 & H4 for NbTaTiZr, C5 & H5 for NbTaTiZrHf, C6 & H6 for NbTaTiZrHfV, and C7 & H7 for NbTaTiZrHfVMo. All specimens were melted and cast in a remelter in an atmosphere of Ar using a water-cooled Cu hearth. As-cast specimens were melted once, and then turned and melted three more times to ensure their homogeneity. Samples were homogenized in a quartz tube that was filled with argon gas at 1100°C for 1 d and then quenched in water.

Figure 1 shows back-scattered electron images (BEI). **Table 1** lists energy-dispersed X-ray spectroscopic (EDS) data for both as-cast and homogenized specimens. White Nb-Ta-rich dendrites and black Ti-Zr-rich interdendrites are observed in C4, and white Nb-Ta-rich dendrites and black Zr-Hf-rich interdendrites are observed in both C5 and C6. XRD patterns (**Figure 2**) reveal that alloys C4 to C6 are simple

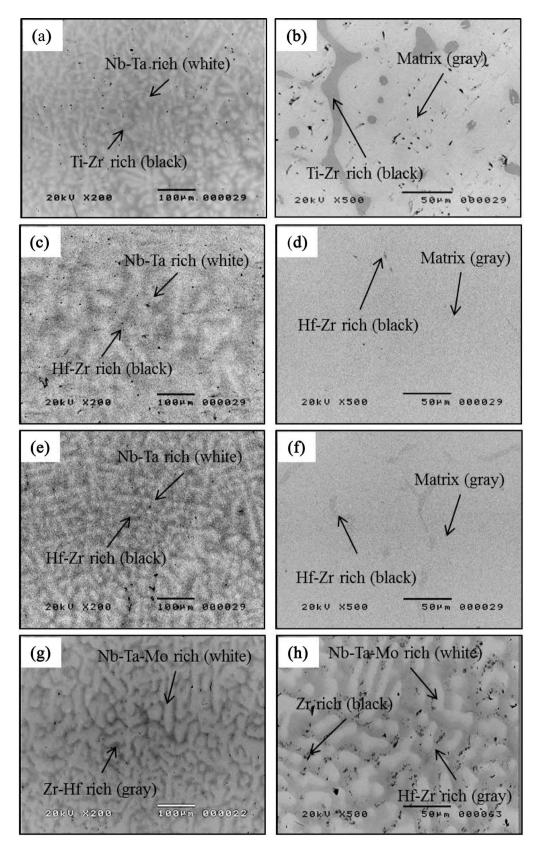


Figure 1. The back-scattered electron images (BEI) for as-cast and homogenized HEAs. (a) C4, (b) H4, (c) C5, (d) H5, (e) C6, (f) H6, (g) C7, (h) H7.

Table 1. Compositions (at%) of selected alloy materials and their phases.

Sample	Phase		Ta	Ti	Zr	Hf	V	Mo
C4	Dendrite (Nb-Ta rich)		30.7	21.3	22.8			
C4	Interdendrite (Ti-Zr rich)		18.1	26.3	36.2			
H4	Matrix	26.1	25.1	23.4	25.4			
114	Interdendrite (Ti-Zr rich)	21.1	16.3	24.3	38.3			
C5	Dendrite (Nb-Ta rich)	22.1	26.3	16.6	15.5	19.5		
C5	Interdendrite (Zr-Hf rich)	16.7	14.3	20.4	25.2	23.4		
115	Matrix	19.8	18.9	20.8	18.7	21.8		
H5	Interdendrite (Zr-Hf rich)	16.6	18.2	20.6	21.5	23.1		
C6	Dendrite (Nb-Ta rich)	21.5	18.1	15.9	14.4	16.6	13.5	
Co	Interdendrite (Zr-Hf rich)	16.8	11.5	16.3	19.7	18.3	17.4	
ш	Matrix	16.3	15.7	16.9	17.1	17.5	16.5	
Н6	Interdendrite (Hf-V rich)	7.4	8.4	7.1	26.3	22.8	27.0	
	Dendrite (Nb-Ta-Mo rich)	17.1	15.2	13.5	11.8	13.9	12.9	15.6
C7	Interdendrite (Zr-Hf rich)	11.4	6.8	16.1	22.7	19.5	14.6	8.9
	Inner-Interdendrite (Zr-Hf rich)		5.8	14.9	26.9	20.5	14.0	8.3
	Dendrite (Nb-Ta-Mo rich) Interdendrite (Zr-Hf rich)		22.6	11.7	6.4	9.5	11.1	18.9
H7			10.5	14.3	18.7	17.2	14.1	12.1
	Inner-Interdendrite (Zr rich)	12.6	10.9	15.8	21.9	13.9	15.3	9.6

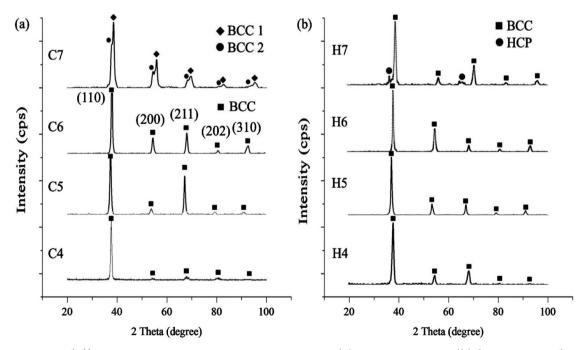


Figure 2. XRD diffraction patterns at room temperature. (a) As-cast HEAs, (b) homogenized HEAs.

pseudo-unitary A2 random BCC solid solutions with lattice parameters of 3.3728 Å, 3.4051 Å, and 3.3567 Å, respectively. H4 to H6 have a matrix, grown from the dendrites, and they contain less interdendrite than the C4 to C6, respectively. The crystal structures and lattice parameters of the as-homogenized samples are almost the same as those of the as-cast samples. Alloys with added Mo, Fe, Ge, Hf, Si, V, and/or W are used to examine the dependence of T_c on the e/a ratio and to verify Matthias' empirical rule. These are NbTaMoW, NbTaMoVW, NbTaTiZrHfVMo (C7 BCC1 & H7 BCC with lattice parameters of 3.2840 & 3.2711 Å, respectively), NbTaTiZrFe, NbTaTiZrGe, NbTaTiZrGeV, NbTaTiZrSiGe, and NbTaTiZrSiGeV.

4. RESULTS AND DISCUSSION

4.1. Measurement of Transition Temperatures

Figure 3 plots the electrical resistivity as a function of temperature from 4.2 K to 300 K in the absence of a magnetic field. C4 to C6 have a superconducting transition at 8.29 \pm 0.04 K, 7.12 \pm 0.02 K, and 5.09 \pm 0.03 K (**Figure 3(a)** to **Figure 3(c)**), respectively, while C7 has no transition in the temperature interval in which measurements are made (**Figure 3(d)**). The transition temperature decreases as Hf and V are added to NbTaTiZr (C4) to form equimolar C5 (C4 + Hf) and C6 (C5 + V) alloys. Following the addition of Mo to C6 to form C7, the alloy undergoes no transition between 4.2 K and 300 K. Therefore the dilution of C4 by Hf, V or Mo reduces the transition temperature. The critical temperatures or T_c values of H4 to H6 samples are, respectively, 8.27 \pm 0.03 K, 6.69 \pm 0.04 K, and 4.96 \pm 0.04 K, which are below the values for the corresponding as-cast alloys (**Figure 4**). Like C7, alloy H7 exhibits no transition in the range 4.2 to 300 K.

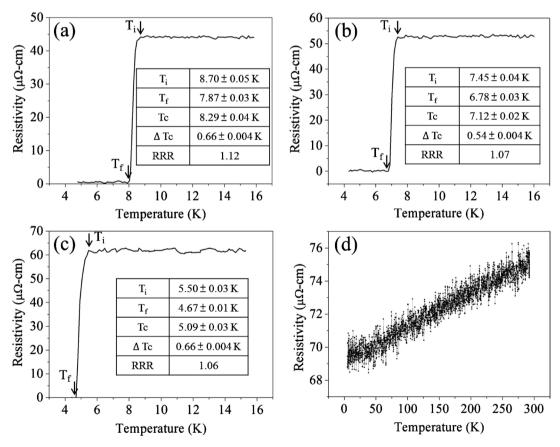


Figure 3. The electrical resistivity as a function of temperature from 4.2 to 300 K in the absence of a magnetic field for as-cast HEAs. (a) C4, (b) C5, (c) C6, (d) C7.

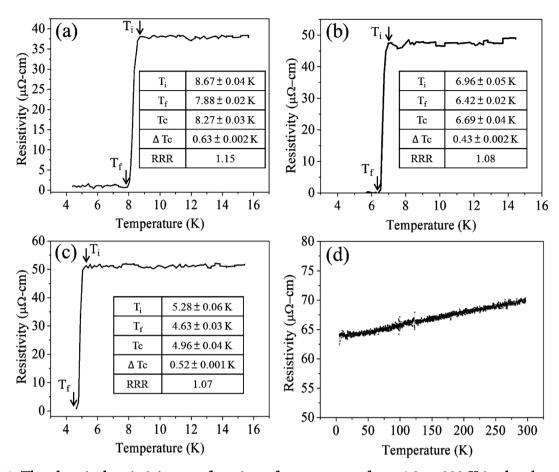


Figure 4. The electrical resistivity as a function of temperature from 4.2 to 300 K in the absence of a magnetic field for homogenized HEAs. (a) H4, (b) H5, (c) H6, (d) H7.

4.1.1. Dependence of Critical Temperature on Microstructure

The major difference between the microstructures of C4 to C6 and that of C7 is that the dendrite phase of the former three alloys (C4 to C6) is Nb-Ta rich, while that of the latter (C7) is Nb-Ta-Mo rich. Both the formation of the Nb-Ta-rich phase in C4 to C6 and that of the Nb-Ta-Mo-rich phase in C7 are attributable to the enthalpy of formation of the elements in the alloys, which are not the focus of this paper. With respect to composition, the total atomic percentages of Nb + Ta in the white phases of the C4 to C7 alloys are, respectively, 55.9, 48.4, 39.6, and 32.3 at%. Their corresponding T_c values are 8.29 \pm 0.04 K, 7.12 \pm 0.02 K, 5.09 \pm 0.03 K, and below 4.2 K, respectively. The T_c values are clearly related to the total amounts of Nb + Ta in the C4 to C7 alloys. Other alloys, such as NbTaTiZrGe and NbTaTiZrFe, have 80+ at% and approximately 75 at% of Nb + Ta in their white phases, respectively, with T_c values of 8.46 and 6.87 K. Similar observations have been made of the Nb-Zr system [4] by authors who applied thermal treatments to raise the Nb content in the β matrix phase, and observed higher T_c . In this study, homogenization reduced the total Nb + Ta contents in the Nb-Ta-rich matrix phase, decreasing T_c to less than that of the as-cast state.

The above SC HEAs, like conventional SC alloys, undergo a transition under an interval of temperatures. The width of the interval, ΔT , depends on the purity and the defect concentration of the sample. Homogenized samples have a more uniform composition and contain fewer defects, so they have a smaller ΔT (Figure 4).

4.1.2. T_c as a Function of Electron-to-Atom Ratio (e/a)

Some papers have discussed Matthias' empirical rule, concerning the relationship between T_c and e/a

[6, 17, 19]. Matthias' empirical rule states that T_c depends on e/a in a particular periodical manner. When e/a ratio are in the range of 4.6 to 4.8, there occurs higher T_c . The e/a of each HEA is calculated herein by giving that the e/a values for the IVB, VB, and VIB elements in the Periodic Table of Elements are 4, 5, and 6, respectively, and the calculated e/a values are compared with T_c . The results of the comparison are listed in **Table 2** and plotted in **Figure 5** for comparison with the empirical rule. C4, C5, NbTaMoW and

Table 2. The calculated e/a and T_c values of as-cast HEAs.

As-cast alloys	$T_{c}\left(\mathbf{K}\right)$	Overall e/a	Phases	e/a
NTL T'- T': 7 (C4)	0.20	4.50	White (Nb-Ta rich)	4.559
NbTaTiZr (C4)	8.29	4.50	Black (Ti-Zr)	4.375
NIL T. T. T. T. (OF)	7.10	4.40	White (Nb-Ta rich)	4.484
NbTaTiZrHf (C5)	7.12	4.40	Black (Hf-Zr rich)	4.310
NILT-T:7-IIGI (OC)	5.09	4.50	White (Nb-Ta rich)	4.531
NbTaTiZrHfV (C6)		4.50	Black (Hf-Zr rich)	4.401
		4.70	White (Nb-Mo-Ta rich)	4.764
NbTaTiZrHfVMo (C7)	N.A.		Gray (Hf-Zr rich)	4.506
			Black (Hf-Zr rich)	4.460
			White (Nb-Ta rich)	4.484 4.310 4.531 4.401 4.764 4.506
NbTaTiZrFe	6.87	5.20	Gray (Zr-Fe rich)	5.474
			Black (Ti-Zr rich)	4.905
			White (Nb-Ta rich)	4.835
NbTaTiZrGe	8.46	4.40	Gray (Ti rich)	4.299
			Black (Ge rich)	4.301
			White (Nb-Ta rich)	4.834
NbTaTiZrGeV	8.40	4.50	Gray (Ti-V rich)	4.626
	0.10		Black (Zr-Ge rich)	4.144
			White (Nb-Ta rich)	4.675
NbTaTiZrSiV	4.29	4.50	Gray (Ti-V rich)	4.549
			Black (Zr-Si rich)	4.314
	7.40		White (Nb-Ta rich)	4.779
NbTaTiZrSiGe		4.33	Gray (Nb-Zr-Ge rich)	4.303
			Black (Si rich)	4.213
		4.43	White (Ta-V rich)	4.758
NbTaTiZrSiGeV	N.A.*		Gray (V rich)	4.747
			Black (Si rich)	4.257
NbTaMoW	N.A.*	5.5	White (Ta-W rich)	5.524
			Black (Nb-Mo rich)	5.472
NbTaMoWV	N.A.*	5.4	White (Ta-W rich)	5.450
			Black (Nb-V rich)	5.288

^{*&}quot;N.A." means $T_c < 4.2$ K.

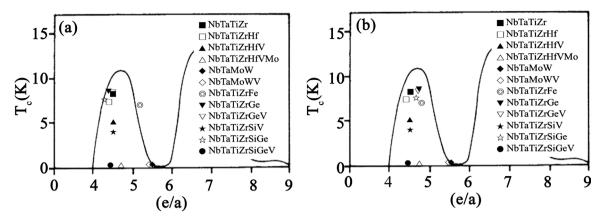


Figure 5. T_c values vs. e/a values for HEAs (Matthias' curve after H.R. Khan). (a) e/a values for overall average composition, (b) e/a values for white-phase composition.

NbTaMoWV qualitatively satisfy the empirical rule (Figure 5(a)). C6, C7, NbTaTiZrFe, NbTaTiZrSiV, and NbTaTiZrSiGeV show point deviation from the empirical curve. As the e/a ratio increases from four to five, T_c increases; as it increases from five to six, T_c falls to below 4.2 K. In an alloy with multiphase or heterogeneous composition, the ratio seems not to be the only indicator of T_c [5]. Values of e/a calculated from the composition of the white phase are presented in Table 2. Both the Nb-Ta-rich "white" phase (C4, C5, C6, NbTaTiZrFe, NbTaTiZrGe, NbTaTiZrGeSi, NbTaTiZrGeV, and NbTaTiZrSiV) and the Nb-Ta-Mo-rich "white" phase (C7) have e/a ratio that is close to the 4.6-4.8-peak in the empirical curve. Therefore, the white phase is concluded to be the SC phase with the highest T_c . The e/a ratio for A2-NbTaMoW and A2-NbTaMoVW are in the range from five to six, so these alloys have lower T_c. The e/a values that are calculated from the compositions of the white phases in alloys C4, C5, C6, NbTaTiZrFe, NbTaTiZrGe, NbTaTiZrGeSi, NbTaTiZrGeV, and NbTaTiZrSiV "match" the empirical curve (Figure 5(b)) with the exception that although e/a is in the range 4.6 to 4.8 for C7 and NbTaTiZrGeSiV, their T_c values are lower than 4.2 K and so could not be observed in this experiment. Interestingly, fewer added elements in the alloys C4 to C7 correspond to higher T_c values. This fact motivates a test of the effect of the lattice distortion (related to number of elements n) on T_c . The root mean square (RMS), as in Equation (15), is used to calculate the degree of lattice distortion. Both lattice expansion and compression are considered because of the square term in this equation.

$$RMS = \sqrt{\frac{\sum_{i=1}^{n} x_i^2}{n}},$$
(15)

where n is the number of elements in the alloy and x_i is the difference between each atomic radius and the mean or equivalent atomic radius that is calculated from the lattice parameter. Since the main lattice structure herein is a pseudo-unitary A2 structure [11], Equation (16) can be utilized to obtain the mean or equivalent atomic radius.

$$4R = \sqrt{3}a, \qquad (16)$$

where "R" is the mean radius and "a" is the lattice parameter. Table 3 presents the values of R, a, and RMS of the HEAs in this study. As n increases, the RMS also increases. This fact, along with the determined values of T_c , reveals that for SC HEAs with a particular e/a, a lower RMS (or lower n) corresponds to a higher T_c . This result is the same as obtained for SC FCC alloys, obtained by Mota and Hoyt [20], who studied alloys of precious metals to which had been added various impurity contents and found that for a fixed e/a value, a higher impurity content caused greater distortion of the FCC lattice and a lower T_c , regardless of whether the distortion was expansive or compressive. The concentration of defects can be evaluated from the RRR (relative residual resistivity) (Figure 3 and Figure 4). As RRR approaches unity, the

Table 3. The values of lattice parameter (Å), R (Å), and RMS/R (%) of as-cast HEAs.

As-cast alloys & alloy designations	R (Å)	Lattice parameter (Å)	RMS/R (%)	
NbTaTiZr (C4)	1.4605	3.3728	4.67	
NbTaTiZrHf (C5)	1.4744	3.4051	4.97	
NbTaTiZrHfV (C6)	1.4535	3.3567	6.12	
NbTaTiZrHfVMo (C7)	1.4343	3.2988	6.48	

effect of the defect concentration on the resistivity becomes stronger. The RRR values of HEAs in this study are near unity, and as n increases, the RRR initially declines, and then increases. However, RRR does not significantly affect T_c in this study.

McMillan proposed Equations ((4) & (5)) and noted that as $D(\varepsilon_F)$ increases and θ_D decreases, λ increases, increasing T_c . Ramakrishnan *et al.* found that ternary Nb₅₀Ti₃₀M $_{20}$ (M = Mo, Pt, Pd, V, and Ru) alloys have a higher θ_D than does Nb₆₀Ti₄₀, and so they have lower values of T_c [21]. An increase of n in HEAs has been suggested to increase θ_D , and reduce T_c . This θ_D factor is responsible for the fact that alloys C7 and NbTaTiZrGeSiV have lower values of T_c . The effect of $D(\varepsilon_F)$ will be discussed.

The SC of HEAs is concluded to depend not only on the distribution of Nb + Ta in the SC phase, but also on the lattice distortion and the consequent change in θ_D

4.2. Magnetization Measurement

4.2.1. χ(T) Curve

SQUID measurements of as-cast alloys were made to study the magnetization of SC HEAs. **Figure 6** plots $\chi(T)$ at 100 Oe for C4 to C7. From **Figure 6**, diamagnetism occurs in C4, C5, C6 and C7 as the temperature falls to 7.86 \pm 0.02 K, 6.37 \pm 0.03 K, 4.96 \pm 0.02 K, and 3.49 \pm 0.03 K, respectively. These first three temperatures are slightly lower than the corresponding T_c values (8.29 \pm 0.04, 7.12 \pm 0.02, and 5.09 \pm 0.03) that were obtained from R(T) in **Figures 3(a)-(c)**, respectively, indicating that an applied magnetic field reduces T_c . Furthermore, at temperatures of greater than T_c at which the diamagnetism disappears and paramagnetism occurs, the χ values for C4, C5, C6 and C7 are independent of temperature during cooling. Therefore, the magnetism of C4 to C7 in their normal conducting (NC) state is Pauli paramagnetism.

4.2.2. M(H) Curve

Figure 7(a) plots M(H) for C4 and C5 at 5 K, and that for C6 at 2 K. These alloys are typical type II SCs. When the applied magnetic field is less than H_{c1} the SC is in the perfect diamagnetic state. The values of H_{c1} are obtained from Equation (14). However, since too few data points are obtained in a weak magnetic field to obtain a precise value of H_{c1} , the H_{c1} values in this study have a slightly large standard deviation. The H_{c1} values of alloys C4 and C5 at 5 K, and of C6 at 2 K, are 664 ± 128 , 77 ± 22 , and 440 ± 155 Oe, respectively. As the number of alloying elements increases, H_{c1} falls. However, C6 has a larger H_{c1} than C5 because H_{c1} is a function of temperature, increasing as the temperature falls. As the applied magnetic field increases above H_{c1} , the % dia-magnetization falls, reaching zero at H_{c2} . The SC-NC mixed state exists between H_{c1} and H_{c2} . In this experiment, the field applied to C4 and C5 was limited to only 1 Tesla (T), and since the H_{c2} values of these alloys exceed 1 T, H_{c2} was not observed. However, extrapolation yielded an H_{c2} in C4 and C5 at 5 K of approximately 1.38 T and 1.85 T, respectively. Since the maximum field that could be applied to C6 was 4 T, its H_{c2} could be obtained 1.93 T at 2 K.

C4 to C7 in normal state show paramagnetism, as can be seen in M(H) at 300 K (**Figure 7(b)**). Because $\chi(T)$ in normal state is independent of T, C4 to C7 are Pauli paramagnetic. Hence, the electron density of state at the Fermi level, $D(\varepsilon_F)$, can be calculated from this Pauli susceptibility, χ_P , by Equation (17) [22]:

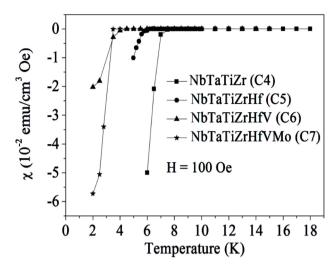


Figure 6. The magnetization as a function of temperature curves, $\chi(T)$, for as-cast HEAs.

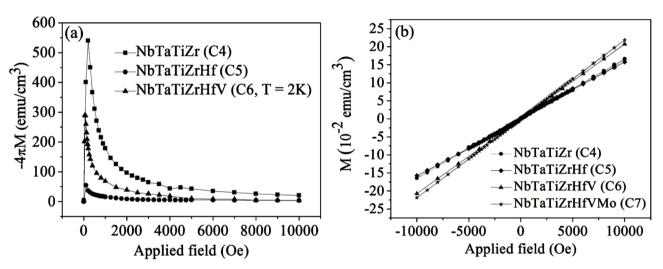


Figure 7. The magnetization as a function of magnetic fields, (M-H), for as-cast HEAs. (a) at T = 5 K, (b) at T = 300 K.

$$\chi_p = \mu_B^2 \times D(\varepsilon_F), \tag{17}$$

where μ_B is the Bohr magneton. Values of χ_p for C4 to C7 are, respectively, 1.65×10^{-5} , 1.56×10^{-5} , 2.07×10^{-5} , and 2.18×10^{-5} emu/cm³·Oe. Clearly, C7 has the largest χ_p and largest $D(\varepsilon_F)$, since χ_p is proportional to $D(\varepsilon_F)$. By Equations ((4) & (5)), higher $D(\varepsilon_F)$ and smaller θ_D yield a higher T_o C7 has the largest $D(\varepsilon_F)$ and the lowest T_o suggesting that it has the largest θ_D .

Figure 8 plots the H_{c2} values of some typical conventional SC alloys and SC HEAs. The equimolar NbTaTiZr-based alloys have lower H_{c2} values than do conventional A-15 alloys. However, the design of HEAs benefits from many degrees of freedom, extensive SC-HEA research is possible.

4.3. Hall Measurements

The calculated carrier density in C5 at 10 K is of the order of 10^{22} cm⁻³—similar to that of pure metals. From the carrier density, electrical conductivity data are calculated (**Table 4**). The Fermi velocities of HEAs are similar to those of pure metals. Since the lattice distortion is greater in HEAs, their 300 K-resistivity is also higher, and the mean free path I of carriers is smaller. The calculated I values satisfy the

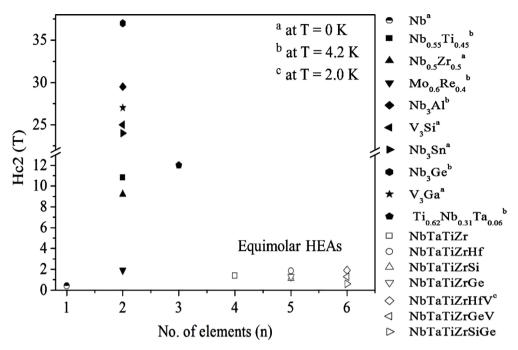


Figure 8. The H_{c2} values for conventional alloys (0 K & 4.2 K) and equimolar HEAs (2 K & 5 K).

Table 4. Electrical conductivity data of alloy C5.

$ ho_{10- ext{K}} \ (\mu\Omega ext{-cm})$	$ ho_{ m 300-K}$ ($\mu\Omega$ -cm)	N_{10-K} (10 ²² cm ⁻³)	<i>T_c</i> (K)	au (10 ⁻¹⁵ s)	v_F (10 ⁸ cm/s)	ℓ (10 ⁻⁷ cm)	$\Delta(0)$ (10^{-3} eV)	<i>ξ</i> ₀ (μm)
52.72	53.67	6.21	7.12	1.07	1.42	1.51	1.08	0.28

condition of "dirty alloys," $l \ll \xi_0$, which is characteristic of type II SCs. The coherence length, ξ , can be expressed as [3]:

$$\xi = \left(\xi_0 \ell\right)^{\frac{1}{2}}.\tag{18}$$

The calculated ξ of C5 is 206.1 Å, which is much larger than the value of YBCO (10 Å) [23]. From Equation (12), the λ of C5 is 2924 Å, so $\kappa (=\lambda/\xi) \sim 14.19$. Accordingly, the HEAs in this study are type II SCs.

5. CONCLUSION

Superconductivity was observed in NbTaTiZr-based HEAs with added Fe, Ge, Hf, Si, and/or V. The SC behavior of HEAs in this study depends on both the composition distribution of Nb + Ta and the degree of lattice distortion that is caused by the change in the number of contained elements, n. As n increases from four to seven, the Nb + Ta content in the SC white phases falls, reducing T_c . In multiphase HEAs, the e/a ratio alone cannot be used to evaluate accurately T_c , as in the manner of the Matthias rule. This study uses analysis of R(T), and SQUID and Hall measurements to demonstrate that the HEAs in this study are type II SCs.

ACKNOWLEDGEMENTS

We acknowledge the financial support of the National Science Council, Taiwan, under No. 100-2221-E-007-110-MY3.

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